

Precision low noise dual operational amplifier

Datasheet -production data

Features

■ Large output voltage swing: +14.3 V/-14.6 V

■ Low input offset voltage 850 µV max.

■ Low voltage noise: 4.5 nV/√Hz

■ High gain bandwidth product: 15 MHz

■ High slew rate: 7 V/µs■ Low distortion: 0.002%

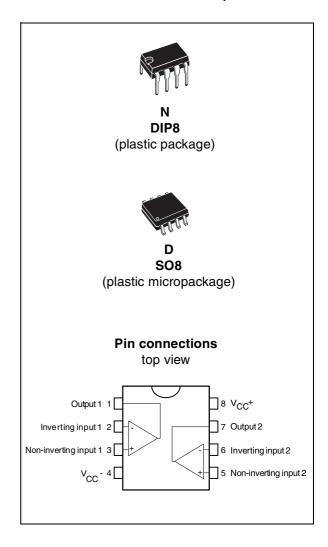
ESD internal protection 2 kV

■ Excellent frequency stability

Description

The TS522 device is a monolithic dual operational amplifier mainly dedicated to audio applications. The TS522 device offers a very low input offset voltage as well as low voltage noise (4.5 nV/√Hz) and high dynamic performances (15 MHz gain bandwidth product, 7 V/µs slew rate).

The output stage allows a large output voltage swing and symmetrical source and sink currents.



1 Absolute maximum ratings and operating conditions

Table 1. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{CC}	Supply voltage	±18 to 36	V
V _{id}	Differential input voltage ⁽¹⁾	±30	V
V _i	Input voltage ⁽¹⁾	±15	V
	Output short-circuit duration ⁽²⁾	Infinite	
Tj	Maximum junction temperature	+ 150	°C
T _{stg}	Storage temperature range	-65 to +150	°C
R _{thja}	Thermal resistance junction-to-ambient ⁽³⁾ , ⁽⁴⁾ SO-8 DIP8	125 85	°C/W
R _{thjc}	Thermal resistance junction-to-case ⁽³⁾ , ⁽⁴⁾ SO-8 DIP8	40 41	°C/W
	HBM: human body model ⁽⁵⁾	2	kV
ESD	MM: machine model ⁽⁶⁾	200	V
	CDM: charged device model ⁽⁷⁾	1.5	kV

- 1. Either or both input voltages must not exceed the magnitude of V_{CC}^+ or V_{CC}^- .
- 2. Power dissipation must be considered to ensure maximum junction temperature (T_i) is not exceeded.
- 3. Short-circuits can cause excessive heating and destructive dissipation.
- 4. R_{th} are typical values.
- Human body model: a 100 pF capacitor is charged to the specified voltage, then discharged through a 1.5 kΩ resistor between two pins of the device. This is done for all couples of connected pin combinations while the other pins are floating.
- 6. Machine model: a 200 pF capacitor is charged to the specified voltage, then discharged directly between two pins of the device with no external series resistor (internal resistor < 5 Ω). This is done for all couples of connected pin combinations while the other pins are floating.
- Charged device model: all pins and the package are charged together to the specified voltage and then discharged directly to ground through only one pin. This is done for all pins.

Table 2. Operating conditions

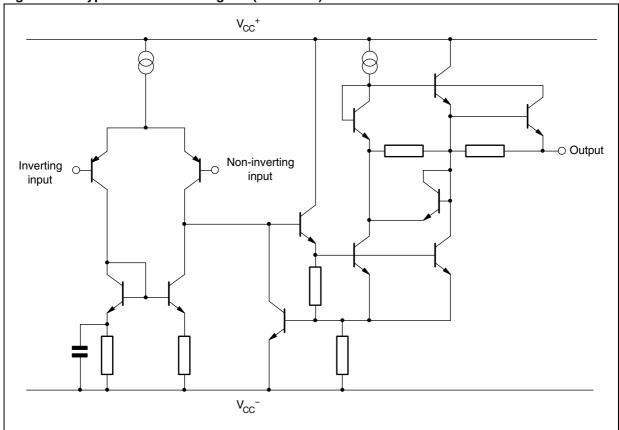
Symbol	Parameter	Value	Unit
V _{CC}	Supply voltage	±2.5 to ±15	V
T _{oper}	Operating free air temperature range	-40 to 125	°C



TS522 Schematic diagram

2 Schematic diagram

Figure 1. Typical schematic diagram (1/2 TS522)



Electrical characteristics TS522

3 Electrical characteristics

Table 3. Electrical characteristics at V_{CC} + = 15 V, V_{CC} - = -15 V, T_{amb} = 25 °C (unless otherwise specified)

Symbol	Parameter	Min.	Тур.	Max.	Unit
V _{io}	Input offset voltage ($V_0 = 0 \text{ V}, V_{ic} = 0 \text{ V}$) $T_{amb} = +25 \text{ °C}$ $T_{min} \le T_{amb} \le T_{max}$			0.85 1.7	mV
ΔV_{io}	Input offset voltage drift $V_{ic} = 0 \text{ V, } V_o = 0 \text{ V, } T_{min} \ \leq T_{amb} \ \leq T_{max}$		2		μV/°C
I _{io}	Input offset current ($V_{ic} = 0 \text{ V}, V_o = 0 \text{ V}$) $T_{amb} = +25 \text{ °C}$ $T_{min} \leq T_{amb} \leq T_{max}$		10	150 175	nA
l _{ib}	Input bias current ($V_{ic} = 0 \text{ V}, V_o = 0 \text{ V}$) $T_{amb} = +25 \text{ °C}$ $T_{min} \leq T_{amb} \leq T_{max}$		250	750 800	nA
V _{icm}	Common mode input voltage range $(\Delta V_{io} = 5 \text{ mV}, V_o = 0 \text{ V})$	±13	±14		V
A_{vd}	Large signal voltage gain (R _L = 2 k Ω , V _o = ±10 V) $T_{amb} = +25 ^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$	90 85	100		dB
	Output voltage swing (V $_{id}$ = ±1 V) R $_{L}$ = 600 Ω R $_{L}$ = 600 Ω		12.2 -12.7		V
$\pm V_{opp}$	$R_L = 2.0 \text{ k}\Omega$ $R_L = 2.0 \text{ k}\Omega$	13.2	14 -14.2	-13.2	
	$R_L = 10 kΩ$ $R_L = 10 kΩ$	13.5	14.3 -14.6	-14	
CMR	Common mode rejection ratio (V _{ic} = ±13 V)	80	100		dB
SVR	Supply voltage rejection ratio $V_{CC}^{+}/V_{CC}^{-} = +15 \text{ V}/-15 \text{ V to } +5 \text{ V}/-5 \text{ V}$	80	105		dB
I _o	Output short-circuit current (V _{id} = ±1 V, output to ground) Source Sink	15 20	29 37		mA
I _{CC}	Supply current ($V_o = 0$ V, all amplifiers) $T_{amb} = +25 ^{\circ}\text{C}$ $T_{min} \leq T_{amb} \leq T_{max}$		4	5 5.5	mA
SR	Slew rate (V _i = -10 V to +10 V, R _L = 2 k Ω , C _L = 100 pF, A _V = +1)	5	7		V/µs
GBP	Gain bandwidth product (f = 100 kHz, $R_L = 2 k\Omega$, $C_L = 100 pF$)	10	15		MHz
В	Unity gain bandwidth (open loop)		9		MHz

Table 3. Electrical characteristics at V_{CC} + = 15 V, V_{CC} - = -15 V, T_{amb} = 25 °C (unless otherwise specified) (continued)

Symbol	Parameter	Min.	Тур.	Max.	Unit
A _m	Gain margin ($R_L = 2 \text{ k}\Omega$) $C_L = 0 \text{ pF}$ $C_L = 100 \text{ pF}$		-11 -6		dB
Øm	Phase margin C _L = 0 pF C _L = 100 pF		55 30		Degre es
e _n	Equivalent input noise voltage $(R_s = 100 \Omega, f = 1 \text{ kHz})$		4.5		<u>nV</u> √Hz
i _n	Equivalent input noise current (f = 1 kHz)		0.5		<u>pA</u> √Hz
THD	Total harmonic distortion $R_L = 2 \ k\Omega$, $f = 20 \ Hz$ to 20 kHz, $V_o = 3 \ V_{rms}$, $A_v = +1$		0.002		%
V ₀₁ /V ₀₂	Channel separation (f = 20 Hz to 20 kHz)		120		dB
FPB	Full power bandwidth $(V_{o}=27\ V_{pp},\ R_{L}=2\ k\Omega\ THD\ \leq1\%)$		120		kHz
Z _o	Output impedance (V _o = 0 V, f = 9 MHz)		37		Ω
R _i	Input resistance (V _{ic} = 0 V)		175		kΩ
C _i	Input capacitance (V _{ic} = 0 V)		12		pF

Electrical characteristics TS522

Figure 2. Total supply current vs. supply voltage

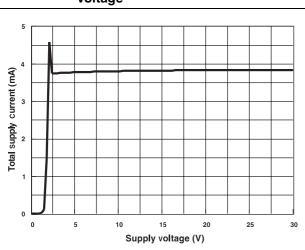


Figure 3. Output short-circuit current vs. output voltage

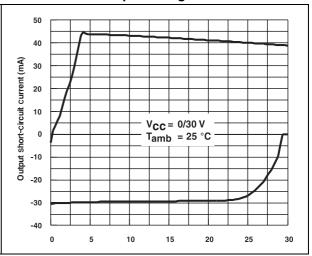


Figure 4. Output voltage vs. supply voltage ($V_{id} = \pm 1$ V, $R_L = 600 \Omega$)

 $(V_{id} = \pm 1 \ V, R_L = 600 \ \Omega)$ 15

10 $(N_i) = \pm 1 \ V$ $(N_i) = 1 \ V$ (

Figure 5. Output voltage vs. supply voltage (V $_{id}$ = ± 1 V, R $_{L}$ = 2 k Ω)

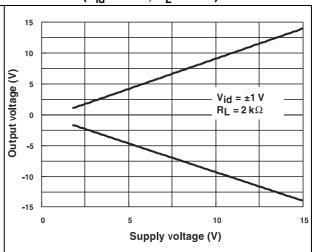


Figure 6. Equivalent input noise voltage vs. frequency

Frequency (kHz)

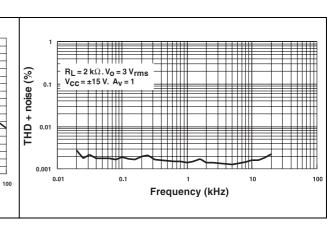


Figure 7. THD + noise vs. frequency

Equivalent input noise voltage

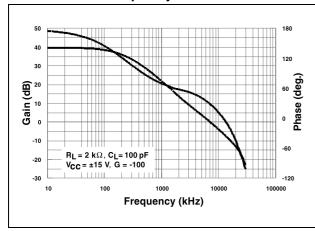
(uV/SQR(Hz))

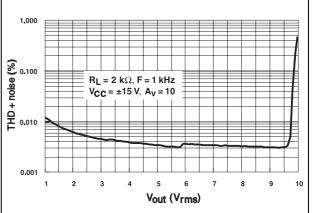
0.01

 $V_{CC} = \pm 15 \text{ V}, \text{ G} = 100 \\ R_S = 100, T_{amb} = 25 ^{\circ}\text{C}$

Figure 8. Voltage gain and phase vs. frequency

Figure 9. THD + noise vs. V_{out}





Package information TS522

4 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.



TS522 Package information

Figure 10. DIP8 package outline

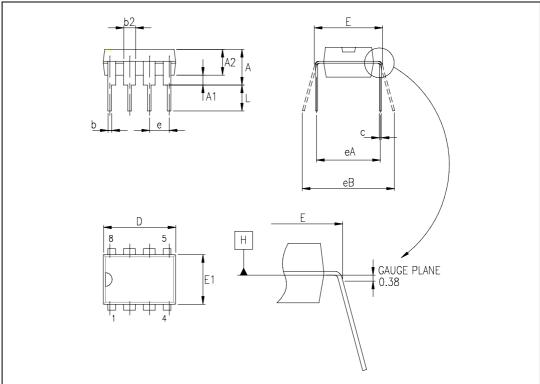


Table 4. DIP8 package mechanical data

	Dimensions						
Symbol	Millimeters			Inches			
	Min.	Тур.	Max.	Min.	Тур.	Max.	
Α		3.32			0.131		
a1	0.51			0.020			
В	1.15		1.65	0.045		0.065	
b	0.356		0.55	0.014		0.022	
b1	0.204		0.304	0.008		0.012	
D			10.92			0.430	
E	7.95		9.75	0.313		0.384	
е		2.54			0.100		
e3		7.62			0.300		
e4		7.62			0.300		
F			6.6			0260	
i			5.08			0.200	
L	3.18		3.81	0.125		0.150	
Z			1.52			0.060	

Package information TS522

Figure 11. SO-8 package outline

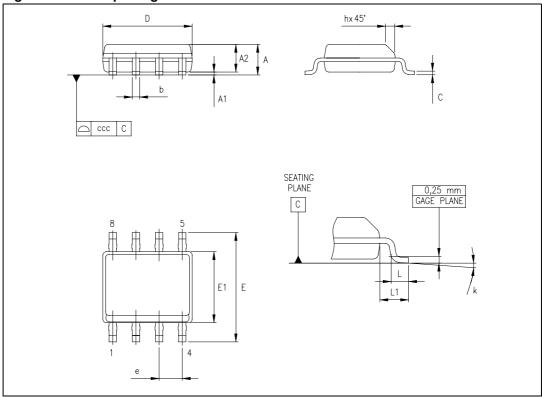


Table 5. SO-8 package mechanical data

	Dimensions					
Symbol	Millimeters			Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α			1.75			0.069
A1	0.10		0.25	0.004		0.010
A2	1.25			0.049		
b	0.28		0.48	0.011		0.019
С	0.17		0.23	0.007		0.010
D	4.80	4.90	5.00	0.189	0.193	0.197
E	5.80	6.00	6.20	0.228	0.236	0.244
E1	3.80	3.90	4.00	0.150	0.154	0.157
е		1.27			0.050	
h	0.25		0.50	0.010		0.020
L	0.40		1.27	0.016		0.050
L1		1.04			0.040	
k	1°		8°	1°		8°
CCC			0.10			0.004

5 Ordering information

Table 6. Order codes

Order code	Temperature range	Package	Packing	Marking	
TS522ID/DT	-40 to +125 °C	SO-8	Tube/tape and reel	5221	
TS522IN -40 to +125 °C		DIP8	Tube	TS522IN	
TS522IYDT ⁽¹⁾	-40 to +125 °C	SO-8 (automotive grade)	Tube/tape and reel	522IY	

Qualified and characterized according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 and Q 002 or equivalent.

6 Revision history

Table 7. Document revision history

Date	Revision	Changes
01-Nov-2001	1	Initial release.
14-Oct-2008	2	Document reformatted. Added automotive grade order codes in <i>Table 6: Order codes</i> . Removed macromodel.
12-Sep-2012 3		Updated Features (removed "Macromodel"). Removed TS522IYD order code from Table 6. Updated ECOPACK text in Section 4. Minor corrections throughout document.

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